

I Number	Hits	Search Text	DB	Time stamp
5	1		USPAT	2003/02/24 09:14
6	1		USPAT	2003/02/24 09:15
7	1		USPAT	2003/02/24 09:16
8	1	("6376896").PN.	USPAT	2003/02/24 09:26
9	7	("4210996"   "4496935"   "5128731"   "5235312"   "5554873"   "5554989"   "5666007").PN.	USPAT	2003/02/24 09:27
-	1	"5081515".PN.	USPAT	2003/02/21 14:43
-	1	"5525530".PN.	USPAT	2003/02/21 14:43
-	1	"5119162".PN.	USPAT	2003/02/21 14:52
-	1	"5148255".PN.	USPAT	2003/02/21 14:52
-	1	"5169794".PN.	USPAT	2003/02/21 14:52
-	1	"5169794".PN.	USPAT	2003/02/21 14:52
-	1	"5216217".PN.	USPAT	2003/02/21 14:52
-	597	cmos same resistor and p near2 gate	USPAT	2003/02/23 15:17
-	3	cmos same resistor and p adj doped near2 gate	USPAT	2003/02/23 12:47
-	795	gate adj electrode near2 "p-type"	USPAT	2003/02/23 13:15
-	155	gate adj electrode near2 "p-type" and resistor	USPAT	2003/02/23 13:31
-	31	gate adj electrode near2 "p-type" and resistor	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/23 14:02
-	1	("5710454").PN.	USPAT	2003/02/23 14:03
-	3	complementary adj fet adj devices	IBM_TDB	2003/02/23 14:06
-	1	"p-resistor" and "n-resistor" and transistor and voltage adj dividing adj circuit	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/23 15:21
-	2	"p-resistor" and "n-resistor" and transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/23 15:21
-	59	p near1 resistor and n near1 resistor and transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/24 09:26

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